

# 74AUP2G04

## Low-power dual inverter

Rev. 6 — 17 September 2015

Product data sheet

## 1. General description

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The 74AUP2G04 provides two inverting buffers.

Schmitt trigger action at all inputs makes the circuit tolerant of slower input rise and fall times across the entire  $V_{CC}$  range from 0.8 V to 3.6 V.

This device ensures a very low static and dynamic power consumption across the entire  $V_{CC}$  range from 0.8 V to 3.6 V.

This device is fully specified for partial power-down applications using  $I_{OFF}$ . The  $I_{OFF}$  circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

## 2. Features and benefits

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- Wide supply voltage range from 0.8 V to 3.6 V
- High noise immunity
- Complies with JEDEC standards:
  - ◆ JESD8-12 (0.8 V to 1.3 V)
  - ◆ JESD8-11 (0.9 V to 1.65 V)
  - ◆ JESD8-7 (1.2 V to 1.95 V)
  - ◆ JESD8-5 (1.8 V to 2.7 V)
  - ◆ JESD8-B (2.7 V to 3.6 V)
- ESD protection:
  - ◆ HBM JESD22-A114F Class 3A exceeds 5000 V
  - ◆ MM JESD22-A115-A exceeds 200 V
  - ◆ CDM JESD22-C101E exceeds 1000 V
- Low static power consumption;  $I_{CC} = 0.9 \mu A$  (maximum)
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Inputs accept voltages up to 3.6 V
- Low noise overshoot and undershoot < 10 % of  $V_{CC}$
- $I_{OFF}$  circuitry provides partial power-down mode operation
- Multiple package options
- Specified from  $-40\text{ }^{\circ}\text{C}$  to  $+85\text{ }^{\circ}\text{C}$  and  $-40\text{ }^{\circ}\text{C}$  to  $+125\text{ }^{\circ}\text{C}$



3. Ordering information

Table 1. Ordering information

| Type number | Package           |        |                                                                                                     |         |
|-------------|-------------------|--------|-----------------------------------------------------------------------------------------------------|---------|
|             | Temperature range | Name   | Description                                                                                         | Version |
| 74AUP2G04GW | −40 °C to +125 °C | SC-88  | plastic surface-mounted package; 6 leads                                                            | SOT363  |
| 74AUP2G04GM | −40 °C to +125 °C | XSON6  | plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1.45 × 0.5 mm         | SOT886  |
| 74AUP2G04GF | −40 °C to +125 °C | XSON6  | plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1 × 0.5 mm            | SOT891  |
| 74AUP2G04GN | −40 °C to +125 °C | XSON6  | extremely thin small outline package; no leads; 6 terminals; body 0.9 × 1.0 × 0.35 mm               | SOT1115 |
| 74AUP2G04GS | −40 °C to +125 °C | XSON6  | extremely thin small outline package; no leads; 6 terminals; body 1.0 × 1.0 × 0.35 mm               | SOT1202 |
| 74AUP2G04GX | −40 °C to +125 °C | X2SON6 | plastic thermal extremely thin small outline package; no leads; 6 terminals; body 1 × 0.8 × 0.35 mm | SOT1255 |

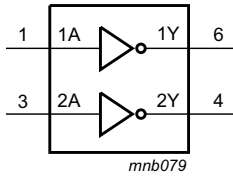
4. Marking

Table 2. Marking

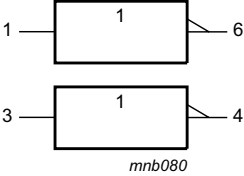
| Type number | Marking code <sup>[1]</sup> |
|-------------|-----------------------------|
| 74AUP2G04GW | p4                          |
| 74AUP2G04GM | p4                          |
| 74AUP2G04GF | p4                          |
| 74AUP2G04GN | p4                          |
| 74AUP2G04GS | p4                          |
| 74AUP2G04GX | p4                          |

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

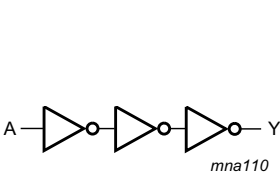
5. Functional diagram



**Fig 1. Logic symbol**



**Fig 2. IEC logic symbol**



**Fig 3. Logic diagram**

6. Pinning information

6.1 Pinning

**Fig 4. Pin configuration SOT363**

**Fig 5. Pin configuration SOT886**

**Fig 6. Pin configuration SOT891, SOT1115 and SOT1202**

**Fig 7. Pin configuration SOT1255 (X2SON6)**

6.2 Pin description

Table 3. Pin description

| Symbol          | Pin | Description    |
|-----------------|-----|----------------|
| 1A              | 1   | data input     |
| GND             | 2   | ground (0 V)   |
| 2A              | 3   | data input     |
| 2Y              | 4   | data output    |
| V <sub>CC</sub> | 5   | supply voltage |
| 1Y              | 6   | data output    |

## 7. Functional description

Table 4. Function table<sup>[1]</sup>

| Input | Output |
|-------|--------|
| nA    | nY     |
| L     | H      |
| H     | L      |

[1] H = HIGH voltage level; L = LOW voltage level.

## 8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol    | Parameter               | Conditions                      | Min  | Max      | Unit |
|-----------|-------------------------|---------------------------------|------|----------|------|
| $V_{CC}$  | supply voltage          |                                 | -0.5 | +4.6     | V    |
| $I_{IK}$  | input clamping current  | $V_I < 0$ V                     | -50  | -        | mA   |
| $V_I$     | input voltage           |                                 | -0.5 | +4.6     | V    |
| $I_{OK}$  | output clamping current | $V_O < 0$ V                     | -50  | -        | mA   |
| $V_O$     | output voltage          | Active mode and Power-down mode | -0.5 | +4.6     | V    |
| $I_O$     | output current          | $V_O = 0$ V to $V_{CC}$         | -    | $\pm 20$ | mA   |
| $I_{CC}$  | supply current          |                                 | -    | 50       | mA   |
| $I_{GND}$ | ground current          |                                 | -50  | -        | mA   |
| $T_{stg}$ | storage temperature     |                                 | -65  | +150     | °C   |
| $P_{tot}$ | total power dissipation | $T_{amb} = -40$ °C to +125 °C   | -    | 250      | mW   |

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SC-88 packages: above 87.5 °C the value of  $P_{tot}$  derates linearly with 4.0 mW/K.  
For X2SON6 and XSON6 packages: above 118 °C the value of  $P_{tot}$  derates linearly with 7.8 mW/K.

## 9. Recommended operating conditions

Table 6. Recommended operating conditions

| Symbol              | Parameter                           | Conditions                      | Min | Max      | Unit |
|---------------------|-------------------------------------|---------------------------------|-----|----------|------|
| $V_{CC}$            | supply voltage                      |                                 | 0.8 | 3.6      | V    |
| $V_I$               | input voltage                       |                                 | 0   | 3.6      | V    |
| $V_O$               | output voltage                      | Active mode                     | 0   | $V_{CC}$ | V    |
|                     |                                     | Power-down mode; $V_{CC} = 0$ V | 0   | 3.6      | V    |
| $T_{amb}$           | ambient temperature                 |                                 | -40 | +125     | °C   |
| $\Delta t/\Delta V$ | input transition rise and fall rate | $V_{CC} = 0.8$ V to 3.6 V       | 0   | 200      | ns/V |

## 10. Static characteristics

**Table 7. Static characteristics**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol                         | Parameter                            | Conditions                                                                                          | Min                    | Typ | Max                    | Unit |
|--------------------------------|--------------------------------------|-----------------------------------------------------------------------------------------------------|------------------------|-----|------------------------|------|
| <b>T<sub>amb</sub> = 25 °C</b> |                                      |                                                                                                     |                        |     |                        |      |
| V <sub>IH</sub>                | HIGH-level input voltage             | V <sub>CC</sub> = 0.8 V                                                                             | 0.70 × V <sub>CC</sub> | -   | -                      | V    |
|                                |                                      | V <sub>CC</sub> = 0.9 V to 1.95 V                                                                   | 0.65 × V <sub>CC</sub> | -   | -                      | V    |
|                                |                                      | V <sub>CC</sub> = 2.3 V to 2.7 V                                                                    | 1.6                    | -   | -                      | V    |
|                                |                                      | V <sub>CC</sub> = 3.0 V to 3.6 V                                                                    | 2.0                    | -   | -                      | V    |
| V <sub>IL</sub>                | LOW-level input voltage              | V <sub>CC</sub> = 0.8 V                                                                             | -                      | -   | 0.30 × V <sub>CC</sub> | V    |
|                                |                                      | V <sub>CC</sub> = 0.9 V to 1.95 V                                                                   | -                      | -   | 0.35 × V <sub>CC</sub> | V    |
|                                |                                      | V <sub>CC</sub> = 2.3 V to 2.7 V                                                                    | -                      | -   | 0.7                    | V    |
|                                |                                      | V <sub>CC</sub> = 3.0 V to 3.6 V                                                                    | -                      | -   | 0.9                    | V    |
| V <sub>OH</sub>                | HIGH-level output voltage            | V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>                                                 |                        |     |                        |      |
|                                |                                      | I <sub>O</sub> = -20 µA; V <sub>CC</sub> = 0.8 V to 3.6 V                                           | V <sub>CC</sub> - 0.1  | -   | -                      | V    |
|                                |                                      | I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V                                                   | 0.75 × V <sub>CC</sub> | -   | -                      | V    |
|                                |                                      | I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V                                                   | 1.11                   | -   | -                      | V    |
|                                |                                      | I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V                                                  | 1.32                   | -   | -                      | V    |
|                                |                                      | I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V                                                   | 2.05                   | -   | -                      | V    |
|                                |                                      | I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V                                                   | 1.9                    | -   | -                      | V    |
|                                |                                      | I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V                                                   | 2.72                   | -   | -                      | V    |
|                                |                                      | I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V                                                   | 2.6                    | -   | -                      | V    |
| V <sub>OL</sub>                | LOW-level output voltage             | V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>                                                 |                        |     |                        |      |
|                                |                                      | I <sub>O</sub> = 20 µA; V <sub>CC</sub> = 0.8 V to 3.6 V                                            | -                      | -   | 0.1                    | V    |
|                                |                                      | I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V                                                    | -                      | -   | 0.3 × V <sub>CC</sub>  | V    |
|                                |                                      | I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V                                                    | -                      | -   | 0.31                   | V    |
|                                |                                      | I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V                                                   | -                      | -   | 0.31                   | V    |
|                                |                                      | I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V                                                    | -                      | -   | 0.31                   | V    |
|                                |                                      | I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V                                                    | -                      | -   | 0.44                   | V    |
|                                |                                      | I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V                                                    | -                      | -   | 0.31                   | V    |
|                                |                                      | I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V                                                    | -                      | -   | 0.44                   | V    |
| I <sub>I</sub>                 | input leakage current                | V <sub>I</sub> = GND to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V                                       | -                      | -   | ±0.1                   | µA   |
| I <sub>OFF</sub>               | power-off leakage current            | V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V                              | -                      | -   | ±0.2                   | µA   |
| ΔI <sub>OFF</sub>              | additional power-off leakage current | V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V;<br>V <sub>CC</sub> = 0 V to 0.2 V                  | -                      | -   | ±0.2                   | µA   |
| I <sub>CC</sub>                | supply current                       | V <sub>I</sub> = GND or V <sub>CC</sub> ; I <sub>O</sub> = 0 A;<br>V <sub>CC</sub> = 0.8 V to 3.6 V | -                      | -   | 0.5                    | µA   |
| ΔI <sub>CC</sub>               | additional supply current            | V <sub>I</sub> = V <sub>CC</sub> - 0.6 V; I <sub>O</sub> = 0 A;<br>V <sub>CC</sub> = 3.3 V          | -                      | -   | 40                     | µA   |
| C <sub>I</sub>                 | input capacitance                    | V <sub>CC</sub> = 0 V to 3.6 V; V <sub>I</sub> = GND or V <sub>CC</sub>                             | -                      | 0.8 | -                      | pF   |
| C <sub>O</sub>                 | output capacitance                   | V <sub>O</sub> = GND; V <sub>CC</sub> = 0 V                                                         | -                      | 1.7 | -                      | pF   |

**Table 7.** Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol                                    | Parameter                            | Conditions                                                                                          | Min                    | Typ | Max                    | Unit |
|-------------------------------------------|--------------------------------------|-----------------------------------------------------------------------------------------------------|------------------------|-----|------------------------|------|
| <b>T<sub>amb</sub> = -40 °C to +85 °C</b> |                                      |                                                                                                     |                        |     |                        |      |
| V <sub>IH</sub>                           | HIGH-level input voltage             | V <sub>CC</sub> = 0.8 V                                                                             | 0.70 × V <sub>CC</sub> | -   | -                      | V    |
|                                           |                                      | V <sub>CC</sub> = 0.9 V to 1.95 V                                                                   | 0.65 × V <sub>CC</sub> | -   | -                      | V    |
|                                           |                                      | V <sub>CC</sub> = 2.3 V to 2.7 V                                                                    | 1.6                    | -   | -                      | V    |
|                                           |                                      | V <sub>CC</sub> = 3.0 V to 3.6 V                                                                    | 2.0                    | -   | -                      | V    |
| V <sub>IL</sub>                           | LOW-level input voltage              | V <sub>CC</sub> = 0.8 V                                                                             | -                      | -   | 0.30 × V <sub>CC</sub> | V    |
|                                           |                                      | V <sub>CC</sub> = 0.9 V to 1.95 V                                                                   | -                      | -   | 0.35 × V <sub>CC</sub> | V    |
|                                           |                                      | V <sub>CC</sub> = 2.3 V to 2.7 V                                                                    | -                      | -   | 0.7                    | V    |
|                                           |                                      | V <sub>CC</sub> = 3.0 V to 3.6 V                                                                    | -                      | -   | 0.9                    | V    |
| V <sub>OH</sub>                           | HIGH-level output voltage            | V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>                                                 |                        |     |                        |      |
|                                           |                                      | I <sub>O</sub> = -20 µA; V <sub>CC</sub> = 0.8 V to 3.6 V                                           | V <sub>CC</sub> - 0.1  | -   | -                      | V    |
|                                           |                                      | I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V                                                   | 0.7 × V <sub>CC</sub>  | -   | -                      | V    |
|                                           |                                      | I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V                                                   | 1.03                   | -   | -                      | V    |
|                                           |                                      | I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V                                                  | 1.30                   | -   | -                      | V    |
|                                           |                                      | I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V                                                   | 1.97                   | -   | -                      | V    |
|                                           |                                      | I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V                                                   | 1.85                   | -   | -                      | V    |
|                                           |                                      | I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V                                                   | 2.67                   | -   | -                      | V    |
|                                           |                                      | I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V                                                   | 2.55                   | -   | -                      | V    |
| V <sub>OL</sub>                           | LOW-level output voltage             | V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>                                                 |                        |     |                        |      |
|                                           |                                      | I <sub>O</sub> = 20 µA; V <sub>CC</sub> = 0.8 V to 3.6 V                                            | -                      | -   | 0.1                    | V    |
|                                           |                                      | I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V                                                    | -                      | -   | 0.3 × V <sub>CC</sub>  | V    |
|                                           |                                      | I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V                                                    | -                      | -   | 0.37                   | V    |
|                                           |                                      | I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V                                                   | -                      | -   | 0.35                   | V    |
|                                           |                                      | I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V                                                    | -                      | -   | 0.33                   | V    |
|                                           |                                      | I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V                                                    | -                      | -   | 0.45                   | V    |
|                                           |                                      | I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V                                                    | -                      | -   | 0.33                   | V    |
|                                           |                                      | I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V                                                    | -                      | -   | 0.45                   | V    |
| I <sub>I</sub>                            | input leakage current                | V <sub>I</sub> = GND to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V                                       | -                      | -   | ±0.5                   | µA   |
| I <sub>OFF</sub>                          | power-off leakage current            | V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V                              | -                      | -   | ±0.5                   | µA   |
| ΔI <sub>OFF</sub>                         | additional power-off leakage current | V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V;<br>V <sub>CC</sub> = 0 V to 0.2 V                  | -                      | -   | ±0.6                   | µA   |
| I <sub>CC</sub>                           | supply current                       | V <sub>I</sub> = GND or V <sub>CC</sub> ; I <sub>O</sub> = 0 A;<br>V <sub>CC</sub> = 0.8 V to 3.6 V | -                      | -   | 0.9                    | µA   |
| ΔI <sub>CC</sub>                          | additional supply current            | V <sub>I</sub> = V <sub>CC</sub> - 0.6 V; I <sub>O</sub> = 0 A;<br>V <sub>CC</sub> = 3.3 V          | -                      | -   | 50                     | µA   |

**Table 7. Static characteristics ...continued**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol                                     | Parameter                            | Conditions                                                                                          | Min                    | Typ | Max                    | Unit |
|--------------------------------------------|--------------------------------------|-----------------------------------------------------------------------------------------------------|------------------------|-----|------------------------|------|
| <b>T<sub>amb</sub> = -40 °C to +125 °C</b> |                                      |                                                                                                     |                        |     |                        |      |
| V <sub>IH</sub>                            | HIGH-level input voltage             | V <sub>CC</sub> = 0.8 V                                                                             | 0.75 × V <sub>CC</sub> | -   | -                      | V    |
|                                            |                                      | V <sub>CC</sub> = 0.9 V to 1.95 V                                                                   | 0.70 × V <sub>CC</sub> | -   | -                      | V    |
|                                            |                                      | V <sub>CC</sub> = 2.3 V to 2.7 V                                                                    | 1.6                    | -   | -                      | V    |
|                                            |                                      | V <sub>CC</sub> = 3.0 V to 3.6 V                                                                    | 2.0                    | -   | -                      | V    |
| V <sub>IL</sub>                            | LOW-level input voltage              | V <sub>CC</sub> = 0.8 V                                                                             | -                      | -   | 0.25 × V <sub>CC</sub> | V    |
|                                            |                                      | V <sub>CC</sub> = 0.9 V to 1.95 V                                                                   | -                      | -   | 0.30 × V <sub>CC</sub> | V    |
|                                            |                                      | V <sub>CC</sub> = 2.3 V to 2.7 V                                                                    | -                      | -   | 0.7                    | V    |
|                                            |                                      | V <sub>CC</sub> = 3.0 V to 3.6 V                                                                    | -                      | -   | 0.9                    | V    |
| V <sub>OH</sub>                            | HIGH-level output voltage            | V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>                                                 |                        |     |                        |      |
|                                            |                                      | I <sub>O</sub> = -20 µA; V <sub>CC</sub> = 0.8 V to 3.6 V                                           | V <sub>CC</sub> - 0.11 | -   | -                      | V    |
|                                            |                                      | I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V                                                   | 0.6 × V <sub>CC</sub>  | -   | -                      | V    |
|                                            |                                      | I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V                                                   | 0.93                   | -   | -                      | V    |
|                                            |                                      | I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V                                                  | 1.17                   | -   | -                      | V    |
|                                            |                                      | I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V                                                   | 1.77                   | -   | -                      | V    |
|                                            |                                      | I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V                                                   | 1.67                   | -   | -                      | V    |
|                                            |                                      | I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V                                                   | 2.40                   | -   | -                      | V    |
|                                            |                                      | I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V                                                   | 2.30                   | -   | -                      | V    |
| V <sub>OL</sub>                            | LOW-level output voltage             | V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>                                                 |                        |     |                        |      |
|                                            |                                      | I <sub>O</sub> = 20 µA; V <sub>CC</sub> = 0.8 V to 3.6 V                                            | -                      | -   | 0.11                   | V    |
|                                            |                                      | I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V                                                    | -                      | -   | 0.33 × V <sub>CC</sub> | V    |
|                                            |                                      | I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V                                                    | -                      | -   | 0.41                   | V    |
|                                            |                                      | I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V                                                   | -                      | -   | 0.39                   | V    |
|                                            |                                      | I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V                                                    | -                      | -   | 0.36                   | V    |
|                                            |                                      | I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V                                                    | -                      | -   | 0.50                   | V    |
|                                            |                                      | I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V                                                    | -                      | -   | 0.36                   | V    |
|                                            |                                      | I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V                                                    | -                      | -   | 0.50                   | V    |
| I <sub>I</sub>                             | input leakage current                | V <sub>I</sub> = GND to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V                                       | -                      | -   | ±0.75                  | µA   |
| I <sub>OFF</sub>                           | power-off leakage current            | V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V                              | -                      | -   | ±0.75                  | µA   |
| ΔI <sub>OFF</sub>                          | additional power-off leakage current | V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V;<br>V <sub>CC</sub> = 0 V to 0.2 V                  | -                      | -   | ±0.75                  | µA   |
| I <sub>CC</sub>                            | supply current                       | V <sub>I</sub> = GND or V <sub>CC</sub> ; I <sub>O</sub> = 0 A;<br>V <sub>CC</sub> = 0.8 V to 3.6 V | -                      | -   | 1.4                    | µA   |
| ΔI <sub>CC</sub>                           | additional supply current            | V <sub>I</sub> = V <sub>CC</sub> - 0.6 V; I <sub>O</sub> = 0 A;<br>V <sub>CC</sub> = 3.3 V          | -                      | -   | 75                     | µA   |

## 11. Dynamic characteristics

**Table 8. Dynamic characteristics**

Voltages are referenced to GND (ground = 0 V); for test circuit see [Figure 9](#).

| Symbol                 | Parameter         | Conditions                                            | 25 °C |                    |      | –40 °C to +125 °C |             |              | Unit |
|------------------------|-------------------|-------------------------------------------------------|-------|--------------------|------|-------------------|-------------|--------------|------|
|                        |                   |                                                       | Min   | Typ <sup>[1]</sup> | Max  | Min               | Max (85 °C) | Max (125 °C) |      |
| C <sub>L</sub> = 5 pF  |                   |                                                       |       |                    |      |                   |             |              |      |
| t <sub>pd</sub>        | propagation delay | nA to nY; see <a href="#">Figure 8</a> <sup>[2]</sup> |       |                    |      |                   |             |              |      |
|                        |                   | V <sub>CC</sub> = 0.8 V                               | -     | 16.0               | -    | -                 | -           | -            | ns   |
|                        |                   | V <sub>CC</sub> = 1.1 V to 1.3 V                      | 2.4   | 5.0                | 10.3 | 2.1               | 11.4        | 12.6         | ns   |
|                        |                   | V <sub>CC</sub> = 1.4 V to 1.6 V                      | 1.8   | 3.6                | 6.4  | 1.6               | 7.4         | 8.2          | ns   |
|                        |                   | V <sub>CC</sub> = 1.65 V to 1.95 V                    | 1.5   | 2.9                | 5.0  | 1.4               | 5.9         | 6.5          | ns   |
|                        |                   | V <sub>CC</sub> = 2.3 V to 2.7 V                      | 1.2   | 2.4                | 3.9  | 1.1               | 4.5         | 5.0          | ns   |
|                        |                   | V <sub>CC</sub> = 3.0 V to 3.6 V                      | 1.1   | 2.1                | 3.2  | 1.0               | 3.9         | 4.3          | ns   |
| C <sub>L</sub> = 10 pF |                   |                                                       |       |                    |      |                   |             |              |      |
| t <sub>pd</sub>        | propagation delay | nA to nY; see <a href="#">Figure 8</a> <sup>[2]</sup> |       |                    |      |                   |             |              |      |
|                        |                   | V <sub>CC</sub> = 0.8 V                               | -     | 19.8               | -    | -                 | -           | -            | ns   |
|                        |                   | V <sub>CC</sub> = 1.1 V to 1.3 V                      | 2.8   | 5.9                | 12.2 | 2.6               | 13.7        | 15.1         | ns   |
|                        |                   | V <sub>CC</sub> = 1.4 V to 1.6 V                      | 2.3   | 4.2                | 7.5  | 2.1               | 8.7         | 9.6          | ns   |
|                        |                   | V <sub>CC</sub> = 1.65 V to 1.95 V                    | 2.0   | 3.5                | 5.9  | 1.8               | 7.0         | 7.7          | ns   |
|                        |                   | V <sub>CC</sub> = 2.3 V to 2.7 V                      | 1.7   | 2.9                | 4.6  | 1.5               | 5.4         | 6.0          | ns   |
|                        |                   | V <sub>CC</sub> = 3.0 V to 3.6 V                      | 1.6   | 2.7                | 3.8  | 1.4               | 4.5         | 5.0          | ns   |
| C <sub>L</sub> = 15 pF |                   |                                                       |       |                    |      |                   |             |              |      |
| t <sub>pd</sub>        | propagation delay | nA to nY; see <a href="#">Figure 8</a> <sup>[2]</sup> |       |                    |      |                   |             |              |      |
|                        |                   | V <sub>CC</sub> = 0.8 V                               | -     | 23.3               | -    | -                 | -           | -            | ns   |
|                        |                   | V <sub>CC</sub> = 1.1 V to 1.3 V                      | 3.2   | 6.7                | 13.0 | 3.0               | 15.8        | 17.4         | ns   |
|                        |                   | V <sub>CC</sub> = 1.4 V to 1.6 V                      | 2.6   | 4.7                | 8.6  | 2.4               | 10.0        | 11.0         | ns   |
|                        |                   | V <sub>CC</sub> = 1.65 V to 1.95 V                    | 2.3   | 4.0                | 6.7  | 2.1               | 8.0         | 8.8          | ns   |
|                        |                   | V <sub>CC</sub> = 2.3 V to 2.7 V                      | 2.1   | 3.3                | 5.1  | 1.8               | 6.1         | 6.8          | ns   |
|                        |                   | V <sub>CC</sub> = 3.0 V to 3.6 V                      | 2.0   | 3.1                | 4.2  | 1.8               | 5.0         | 5.5          | ns   |
| C <sub>L</sub> = 30 pF |                   |                                                       |       |                    |      |                   |             |              |      |
| t <sub>pd</sub>        | propagation delay | nA to nY; see <a href="#">Figure 8</a> <sup>[2]</sup> |       |                    |      |                   |             |              |      |
|                        |                   | V <sub>CC</sub> = 0.8 V                               | -     | 33.6               | -    | -                 | -           | -            | ns   |
|                        |                   | V <sub>CC</sub> = 1.1 V to 1.3 V                      | 4.4   | 8.9                | 16.0 | 4.0               | 19.0        | 20.9         | ns   |
|                        |                   | V <sub>CC</sub> = 1.4 V to 1.6 V                      | 3.6   | 6.3                | 10.8 | 3.2               | 12.9        | 14.2         | ns   |
|                        |                   | V <sub>CC</sub> = 1.65 V to 1.95 V                    | 3.2   | 5.3                | 9.0  | 2.9               | 10.5        | 11.6         | ns   |
|                        |                   | V <sub>CC</sub> = 2.3 V to 2.7 V                      | 2.9   | 4.5                | 6.5  | 2.6               | 7.6         | 8.4          | ns   |
|                        |                   | V <sub>CC</sub> = 3.0 V to 3.6 V                      | 2.9   | 4.2                | 5.4  | 2.6               | 6.2         | 6.9          | ns   |

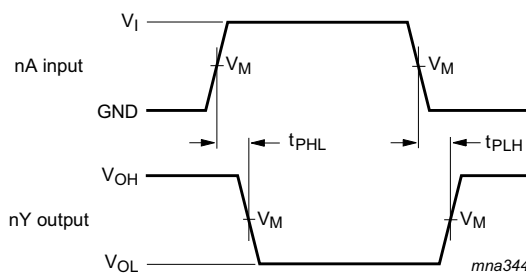
**Table 8.** Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V); for test circuit see [Figure 9](#).

| Symbol                                        | Parameter                     | Conditions                                                                        | 25 °C |                    |     | –40 °C to +125 °C |             |              | Unit |
|-----------------------------------------------|-------------------------------|-----------------------------------------------------------------------------------|-------|--------------------|-----|-------------------|-------------|--------------|------|
|                                               |                               |                                                                                   | Min   | Typ <sup>[1]</sup> | Max | Min               | Max (85 °C) | Max (125 °C) |      |
| C <sub>L</sub> = 5 pF, 10 pF, 15 pF and 30 pF |                               |                                                                                   |       |                    |     |                   |             |              |      |
| C <sub>PD</sub>                               | power dissipation capacitance | f <sub>i</sub> = 1 MHz; V <sub>I</sub> = GND to V <sub>CC</sub> <sup>[3][4]</sup> |       |                    |     |                   |             |              |      |
|                                               |                               | V <sub>CC</sub> = 0.8 V                                                           | -     | 2.5                | -   | -                 | -           | -            | pF   |
|                                               |                               | V <sub>CC</sub> = 1.1 V to 1.3 V                                                  | -     | 2.7                | -   | -                 | -           | -            | pF   |
|                                               |                               | V <sub>CC</sub> = 1.4 V to 1.6 V                                                  | -     | 2.8                | -   | -                 | -           | -            | pF   |
|                                               |                               | V <sub>CC</sub> = 1.65 V to 1.95 V                                                | -     | 3.0                | -   | -                 | -           | -            | pF   |
|                                               |                               | V <sub>CC</sub> = 2.3 V to 2.7 V                                                  | -     | 3.5                | -   | -                 | -           | -            | pF   |
|                                               |                               | V <sub>CC</sub> = 3.0 V to 3.6 V                                                  | -     | 4.0                | -   | -                 | -           | -            | pF   |

- [1] All typical values are measured at nominal V<sub>CC</sub>.
- [2] t<sub>pd</sub> is the same as t<sub>PLH</sub> and t<sub>PHL</sub>.
- [3] All specified values are the average typical values over all stated loads.
- [4] C<sub>PD</sub> is used to determine the dynamic power dissipation (P<sub>D</sub> in μW).  
 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o)$  where:  
 f<sub>i</sub> = input frequency in MHz;  
 f<sub>o</sub> = output frequency in MHz;  
 C<sub>L</sub> = load capacitance in pF;  
 V<sub>CC</sub> = supply voltage in V;  
 N = number of inputs switching;  
 $\Sigma(C_L \times V_{CC}^2 \times f_o)$  = sum of the outputs.

## 12. Waveforms

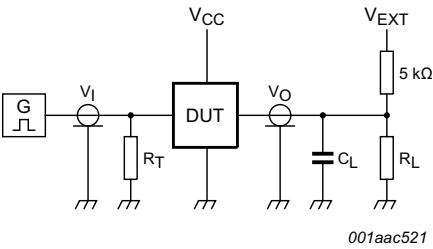


Measurement points are given in [Table 9](#).

Logic levels: V<sub>OL</sub> and V<sub>OH</sub> are typical output voltage levels that occur with the output load.

**Fig 8.** The data input (nA) to output (nY) propagation delays**Table 9.** Measurement points

| Supply voltage  | Output                | Input                 |                 |                                 |
|-----------------|-----------------------|-----------------------|-----------------|---------------------------------|
| V <sub>CC</sub> | V <sub>M</sub>        | V <sub>M</sub>        | V <sub>I</sub>  | t <sub>r</sub> = t <sub>f</sub> |
| 0.8 V to 3.6 V  | 0.5 × V <sub>CC</sub> | 0.5 × V <sub>CC</sub> | V <sub>CC</sub> | ≤ 3.0 ns                        |



Test data is given in [Table 10](#).

Definitions for test circuit:

- $R_L$  = Load resistance.
- $C_L$  = Load capacitance including jig and probe capacitance.
- $R_T$  = Termination resistance should be equal to the output impedance  $Z_o$  of the pulse generator.
- $V_{EXT}$  = External voltage for measuring switching times.

Fig 9. Test circuit for measuring switching times

Table 10. Test data

| Supply voltage | Load                         |                      | $V_{EXT}$             |                       |                       |
|----------------|------------------------------|----------------------|-----------------------|-----------------------|-----------------------|
| $V_{CC}$       | $C_L$                        | $R_L$ <sup>[1]</sup> | $t_{PLH}$ , $t_{PHL}$ | $t_{PZH}$ , $t_{PHZ}$ | $t_{PZL}$ , $t_{PLZ}$ |
| 0.8 V to 3.6 V | 5 pF, 10 pF, 15 pF and 30 pF | 5 kΩ or 1 MΩ         | open                  | GND                   | $2 \times V_{CC}$     |

[1] For measuring enable and disable times,  $R_L = 5\text{ k}\Omega$ . For measuring propagation delays, set-up and hold times, and pulse width,  $R_L = 1\text{ M}\Omega$ .

13. Package outline

Plastic surface-mounted package; 6 leadsSOT363

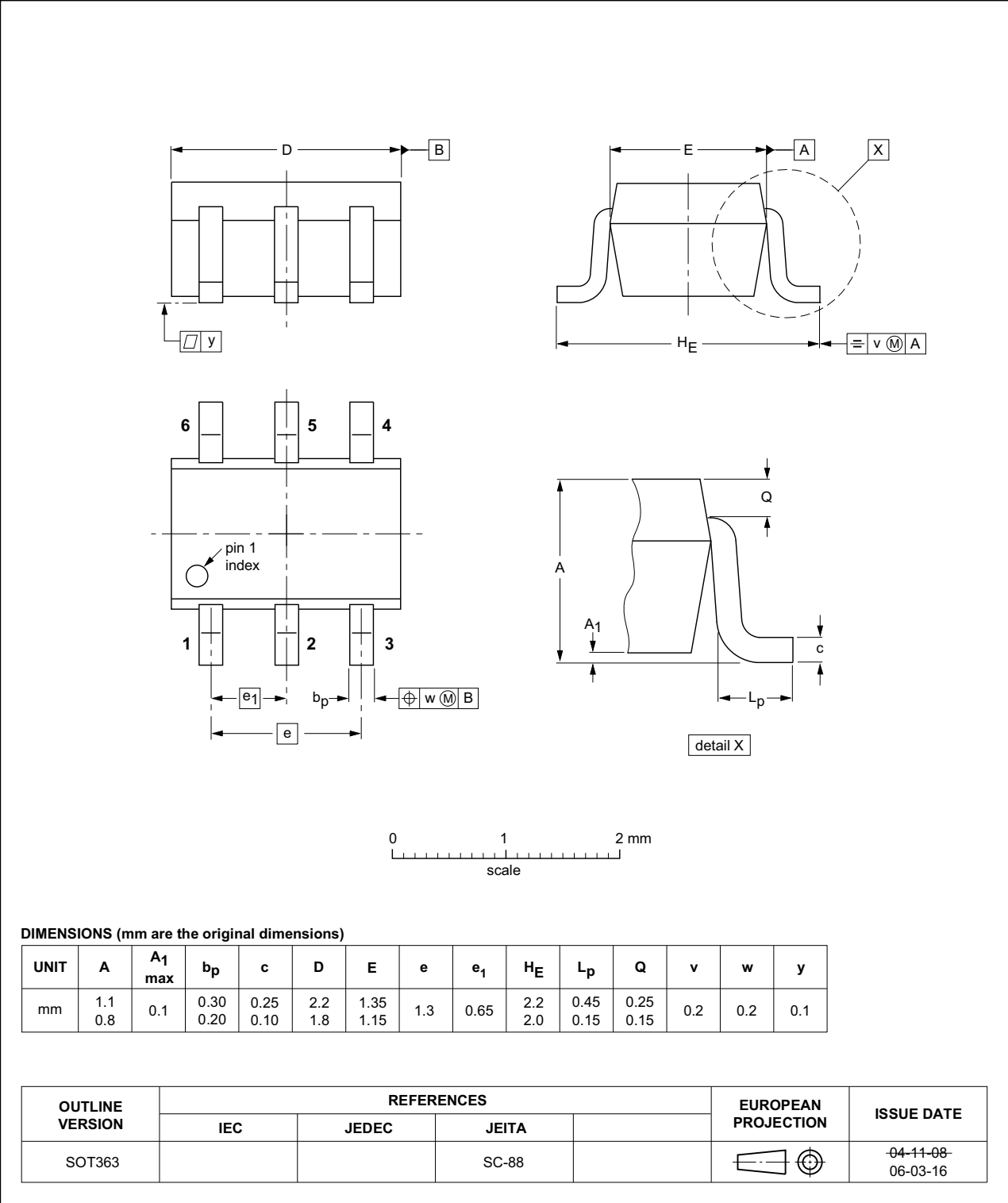


Fig 10. Package outline SOT363 (SC-88)

XSON6: plastic extremely thin small outline package; no leads; 6 terminals; body 1 x 1.45 x 0.5 mm

SOT886

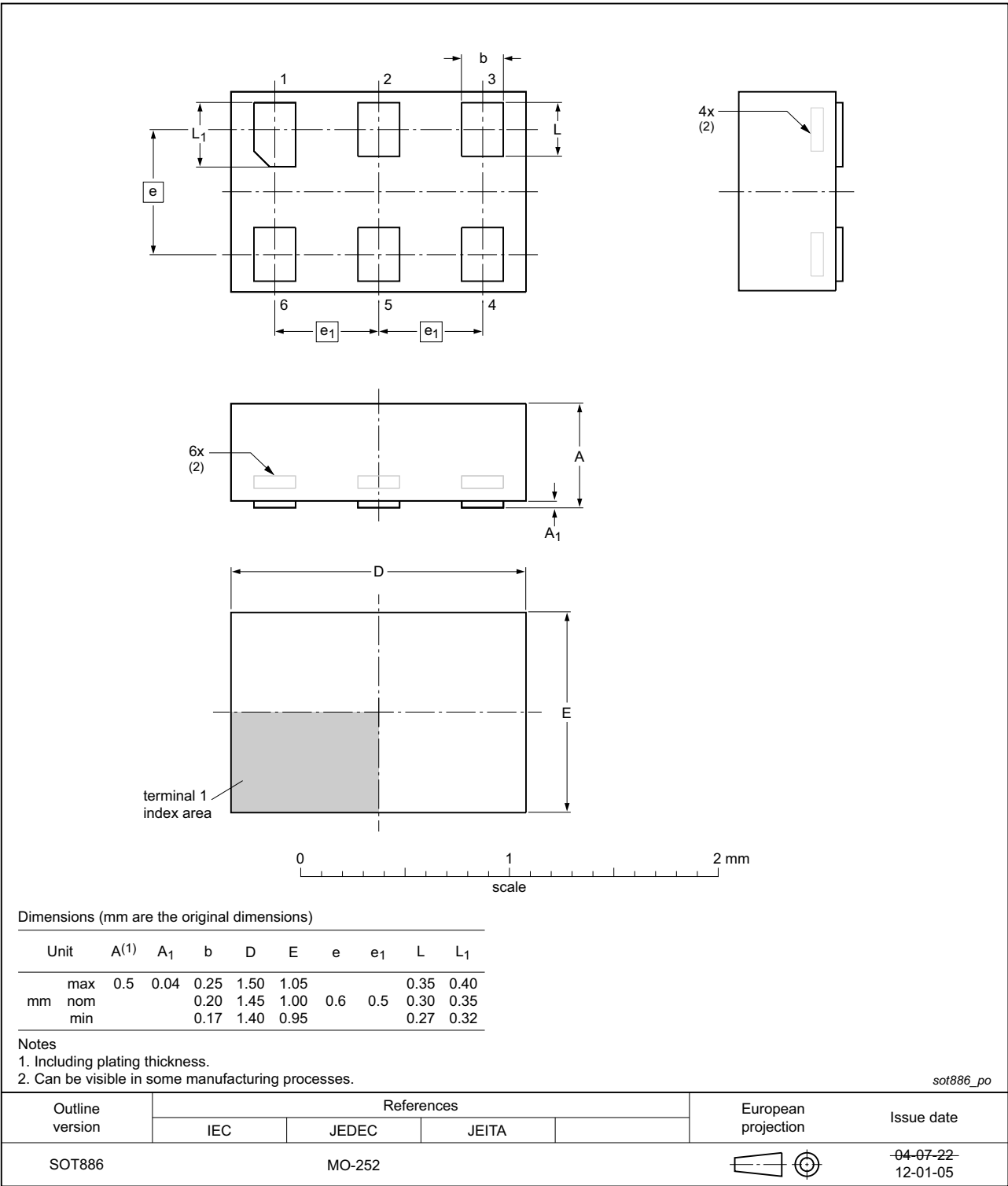


Fig 11. Package outline SOT886 (XSON6)

XSON6: plastic extremely thin small outline package; no leads; 6 terminals; body 1 x 1 x 0.5 mm

SOT891

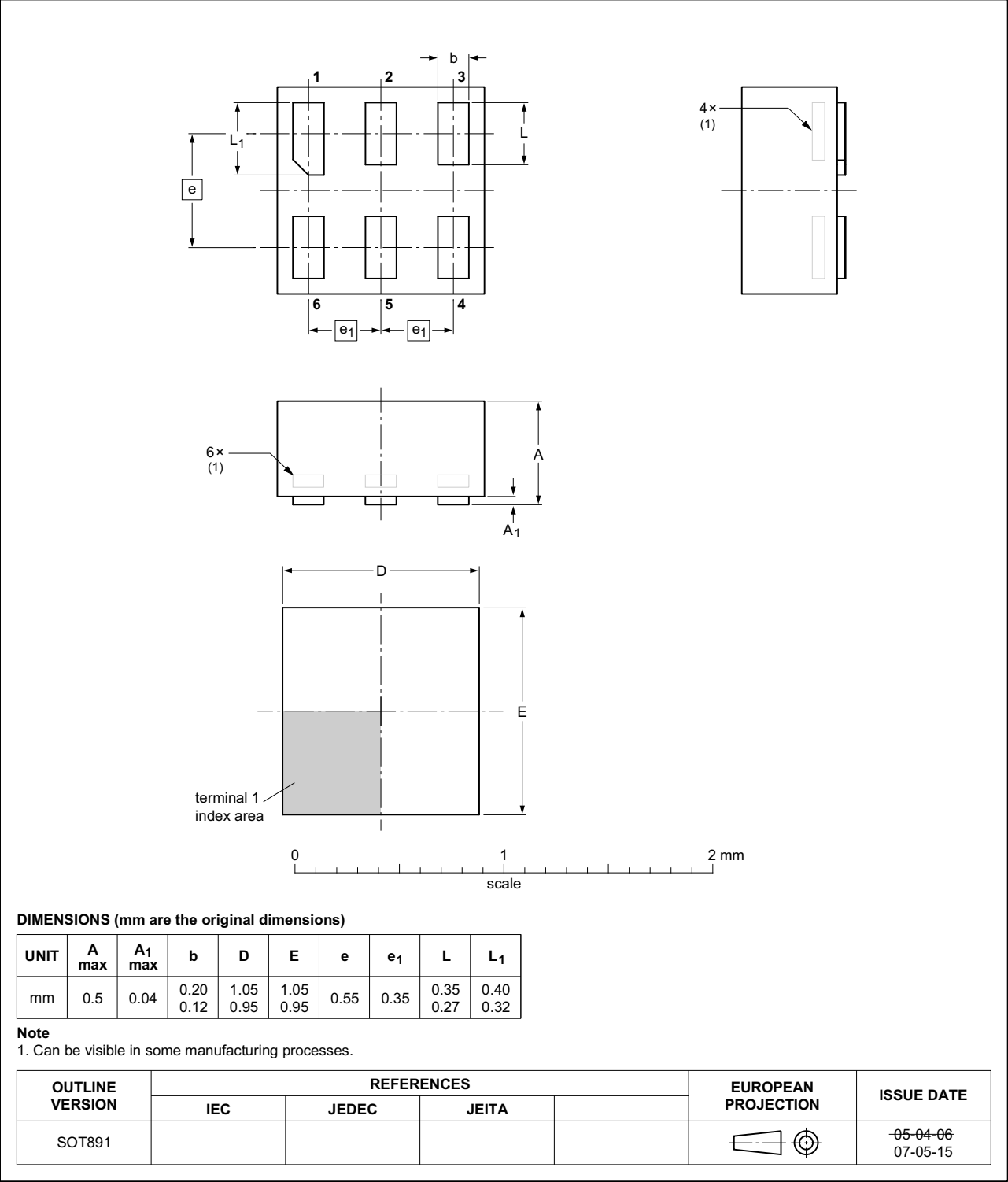


Fig 12. Package outline SOT891 (XSON6)

**XSON6: extremely thin small outline package; no leads;**  
**6 terminals; body 0.9 x 1.0 x 0.35 mm**

SOT1115

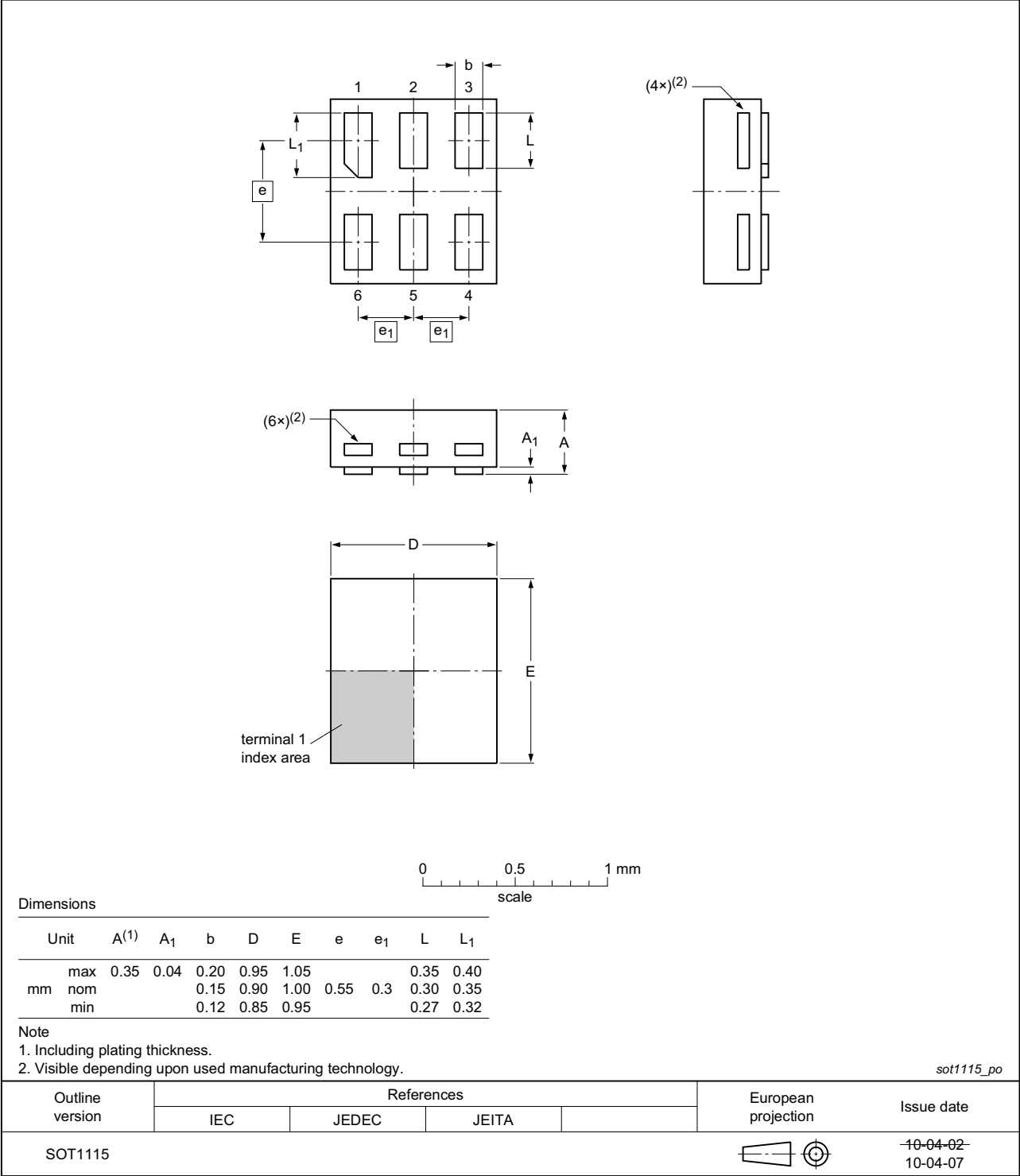


Fig 13. Package outline SOT1115 (XSON6)

XSON6: extremely thin small outline package; no leads;  
6 terminals; body 1.0 x 1.0 x 0.35 mm

SOT1202

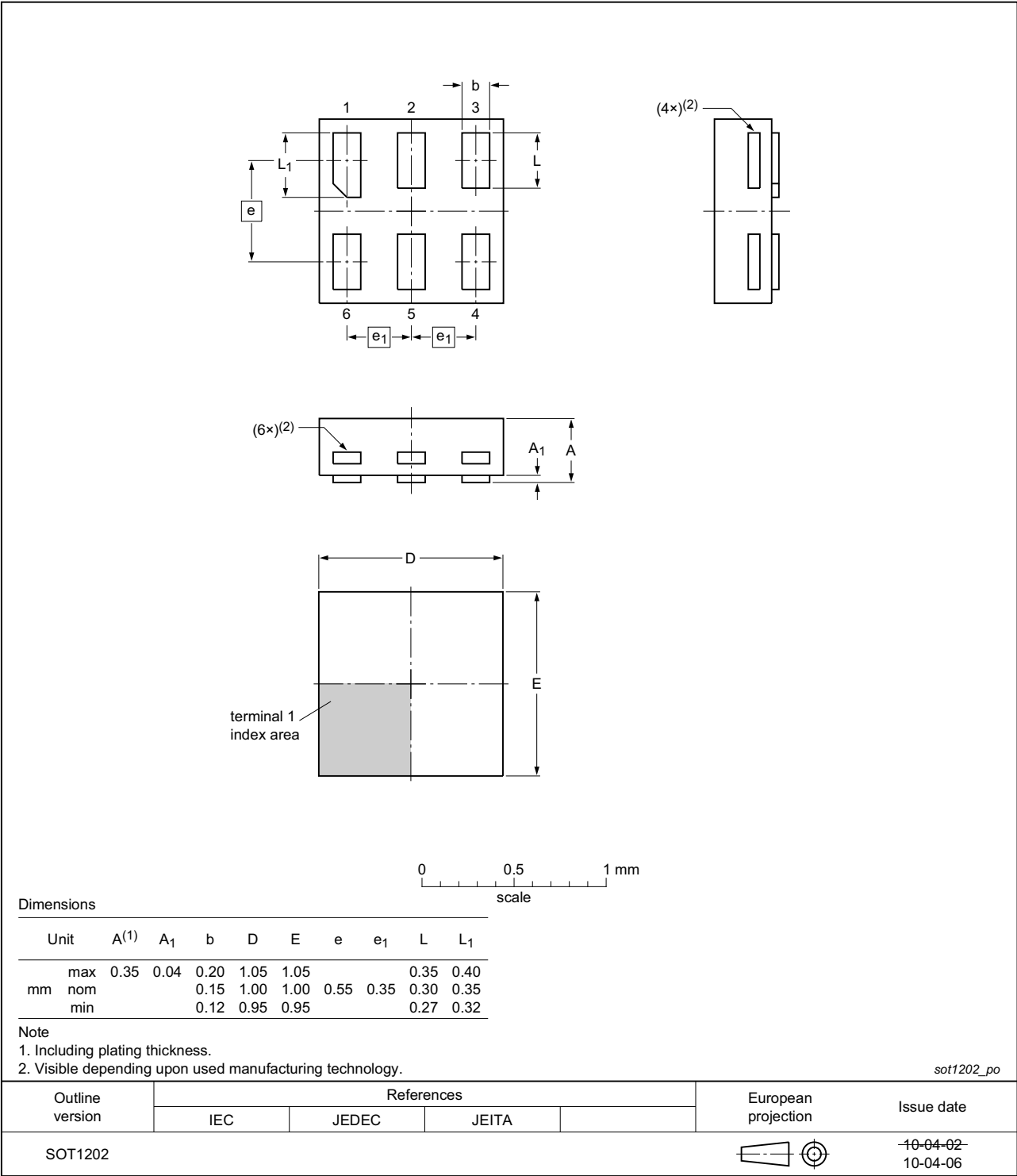


Fig 14. Package outline SOT1202 (XSON6)

**X2SON6: plastic thermal enhanced extremely thin small outline package; no leads;**  
**6 terminals; body 1.0 x 0.8 x 0.35 mm**

SOT1255

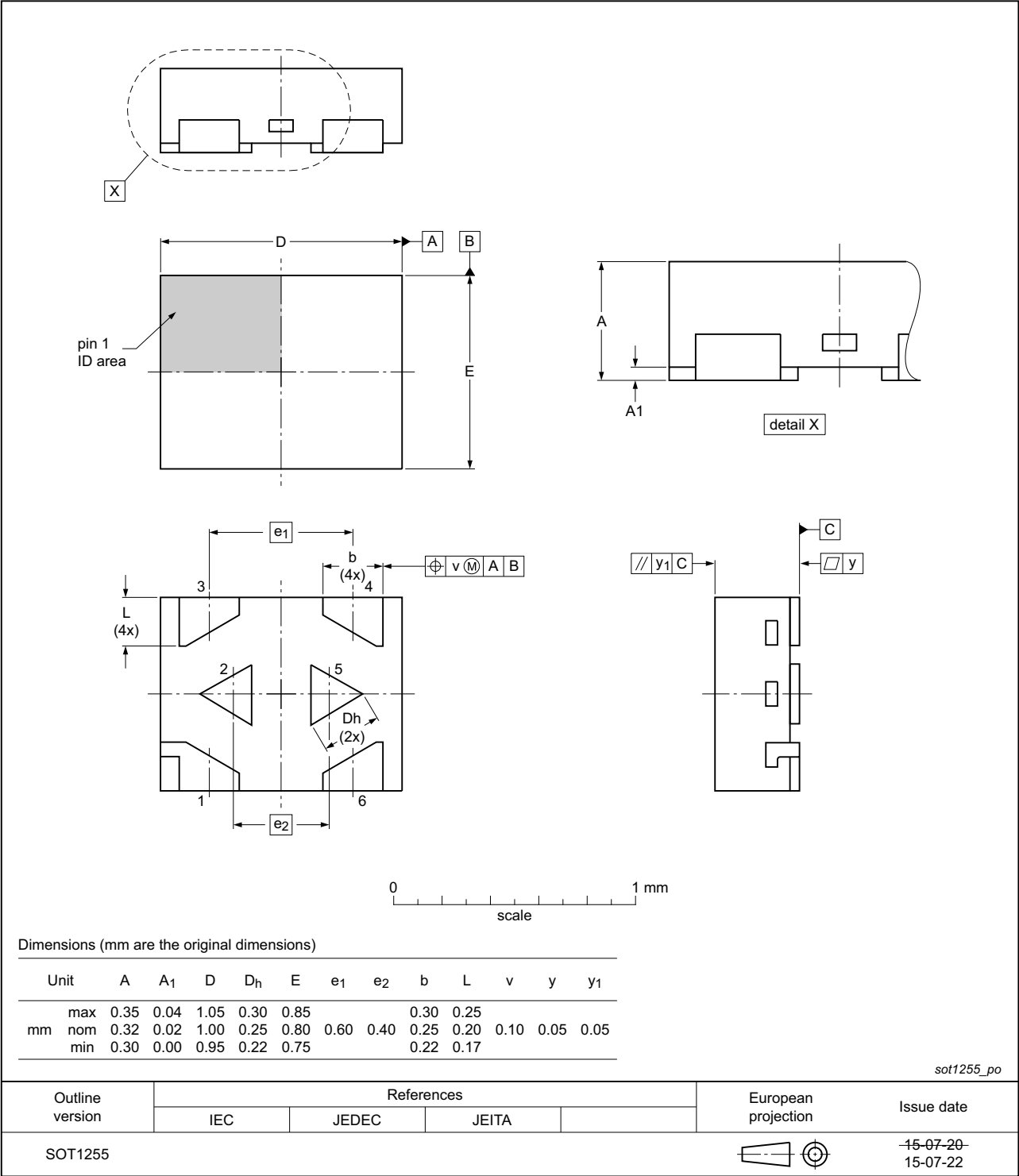


Fig 15. Package outline SOT1255 (X2SON6)

## 14. Abbreviations

Table 11. Abbreviations

| Acronym | Description             |
|---------|-------------------------|
| CDM     | Charged Device Model    |
| DUT     | Device Under Test       |
| ESD     | ElectroStatic Discharge |
| HBM     | Human Body Model        |
| MM      | Machine Model           |

## 15. Revision history

Table 12. Revision history

| Document ID    | Release date                                                                | Data sheet status  | Change notice | Supersedes    |
|----------------|-----------------------------------------------------------------------------|--------------------|---------------|---------------|
| 74AUP2G04 v.6  | 20150917                                                                    | Product data sheet | -             | 74AUP2G04 v.5 |
| Modifications: | • Added type number 74AUP2G04GX (SOT1255/X2SON6).                           |                    |               |               |
| 74AUP2G04 v.5  | 20120305                                                                    | Product data sheet | -             | 74AUP2G04 v.4 |
| Modifications: | • Package outline drawing of SOT886 ( <a href="#">Figure 11</a> ) modified. |                    |               |               |
| 74AUP2G04 v.4  | 20111202                                                                    | Product data sheet | -             | 74AUP2G04 v.3 |
| Modifications: | • Legal pages updated.                                                      |                    |               |               |
| 74AUP2G04 v.3  | 20101101                                                                    | Product data sheet | -             | 74AUP2G04 v.2 |
| 74AUP2G04 v.2  | 20090707                                                                    | Product data sheet | -             | 74AUP2G04 v.1 |
| 74AUP2G04 v.1  | 20061122                                                                    | Product data sheet | -             | -             |

## 16. Legal information

### 16.1 Data sheet status

| Document status <sup>[1][2]</sup> | Product status <sup>[3]</sup> | Definition                                                                            |
|-----------------------------------|-------------------------------|---------------------------------------------------------------------------------------|
| Objective [short] data sheet      | Development                   | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet    | Qualification                 | This document contains data from the preliminary specification.                       |
| Product [short] data sheet        | Production                    | This document contains the product specification.                                     |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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